

SI3493DV-T1-E3

SI3493DV-T1-E3 Information

Con Con	Part Number Manufacturer Category Description Package		
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



SI3493DV-T1-E3 Specifications

Manufacturer Part Number	SI3493DV-T1-E3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	SOT-23-6 Thin, TSOT-23-6
Series	TrenchFET?
FET Type	P-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	20V
Current - Continuous Drain (Id) @ 25°C	5.3A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	1.8V, 4.5V
Vgs(th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	32nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	-
Vgs (Max)	$\pm 8V$
FET Feature	-
Power Dissipation (Max)	1.1W (Ta)
Rds On (Max) @ Id, Vgs	27 mOhm @ 7A, 4.5V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	6-TSOP
Package / Case	SOT-23-6 Thin, TSOT-23-6
	Report errors?

SI3493DV-T1-E3 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

SI3493DV-T1-E3 Payment Methods



SI3493DV-T1-E3 Shipping Methods



If you have any question about SI3493DV-T1-E3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com